TS4900

## 300 mW at 3.3 V SUPPLY AUDIO POWER AMPLIFIER WITH STANDBY MODE ACTIVE HIGH

OPERATING FROM $\mathrm{V}_{\mathrm{cc}}=2.5 \mathrm{~V}$ to 5.5 V
■0.7W OUTPUT POWER @ Vcc=5V, THD=1\%, $\mathrm{f}=1 \mathrm{kHz}$, with an $8 \Omega$ load
■ 0.3W OUTPUT POWER @ Vcc=3.3V, $\mathrm{THD}=1 \%, \mathrm{f}=1 \mathrm{kHz}$, with an $8 \Omega$ load
$\square$ ULTRA LOW CONSUMPTION IN STANDBY MODE (10nA)
■ 75dB PSRR @ 217Hz from 5V to 2.6V
■ ULTRA LOW POP \& CLICK

- ULTRA LOW DISTORTION (0.1\%)
- UNITY GAIN STABLE
- AVAILABLE IN MiniSO8 \& SO8


## DESCRIPTION

The TS4900 is an audio power amplifier designed to provide the best price to power ratio while preserving high audio quality.

Available in MiniSO8 \& SO8 package, it is capable of delivering up to 0.7 W of continuous RMS ouput power into an $8 \Omega$ load @ 5 V .

TS4900 is also exhibiting an outstanding $0.1 \%$ distortion level (THD) from a 5V supply for a Pout of 200 mW RMS.

An externally controlled standby mode control reduces the supply current to less than 10nA. It also includes an internal thermal shutdown protection.

The unity-gain stable amplifier can be configured by external gain setting resistors.

## APPLICATIONS

Mobile Phones (Cellular / Cordless)
PDAs
■ Portable Audio Devices

## ORDER CODE

| Part Number | Temperature <br> Range | Package |  |
| :--- | :---: | :---: | :---: |
|  |  | S | D |
| TS4900IS | $-40,+85^{\circ} \mathrm{C}$ | $\bullet$ |  |
| TS4900ID |  | $\bullet$ |  |

S = MiniSO Package (MiniSO) only available in Tape \& Reel (ST) D = Small Outline Package (SO) - also available in Tape \& Reel (DT)

PIN CONNECTIONS (top view)


TYPICAL APPLICATION SCHEMATIC


ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply voltage ${ }^{1)}$ | 6 | V |
| $\mathrm{~V}_{\mathrm{i}}$ | Input Voltage $^{2)}$ | $\mathrm{G}_{\mathrm{ND}}$ to $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\text {oper }}$ | Operating Free Air Temperature Range | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{j}}$ | Maximum Junction Temperature | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{R}_{\text {thia }}$ | Thermal Resistance Junction to Ambient ${ }^{3)}$ |  | 175 |
|  | SO8 | 215 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  | MiniSO8 | Internally Limited ${ }^{4)}$ |  |
| Pd | Power Dissipation | 2 | kV |
| ESD | Human Body Model | 200 | V |
| ESD | Machine Model | Class A |  |
| Latch-up | Latch-up Immunity | 250 | ${ }^{\circ} \mathrm{C}$ |
|  | Lead Temperature (soldering, 10sec) |  |  |

1. All voltages values are measured with respect to the ground pin.
2. The magnitude of input signal must never exceed $\mathrm{V}_{\mathrm{CC}}+0.3 \mathrm{~V} / \mathrm{G}_{\mathrm{ND}}-0.3 \mathrm{~V}$
3. Device is protected in case of over temperature by a thermal shutdown active @ $150^{\circ} \mathrm{C}$.
4. Exceeding the power derating curves during a long period, will cause abnormal operation.

## OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Supply Voltage | 2.5 to 5.5 | V |
| $\mathrm{~V}_{\text {ICM }}$ | Common Mode Input Voltage Range | $\mathrm{G}_{\mathrm{ND}}$ to $\mathrm{V}_{\mathrm{CC}}-1.5 \mathrm{~V}$ | V |
| $\mathrm{~V}_{\mathrm{STB}}$ | Standby Voltage Input : <br> Device ON <br> Device OFF | $\mathrm{G}_{\mathrm{ND}} \leq \mathrm{V}_{\mathrm{STB}} \leq 0.5 \mathrm{~V}$ <br> $\mathrm{~V}_{\mathrm{CC}}-0.5 \mathrm{~V} \leq \mathrm{V}_{\text {STB }} \leq \mathrm{V}_{\mathrm{CC}}$ | V |
| $\mathrm{R}_{\mathrm{L}}$ | Load Resistor | $4-32$ | $\Omega$ |
| $\mathrm{R}_{\text {thia }}$ | Thermal Resistance Junction to Ambient ${ }^{1)}$ <br> SO8 <br> MiniSO8 | 150 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | 190 |  |

[^0]
## ELECTRICAL CHARACTERISTICS

$\mathrm{V}_{\mathrm{CC}}=+\mathbf{5 V}, G N D=\mathbf{0}, \mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{CC}}$ | Supply Current No input signal, no load |  | 6 | 8 | mA |
| $I_{\text {StandBy }}$ | Standby Current ${ }^{1)}$ <br> No input signal, Vstdby $=\mathrm{Vcc}, \mathrm{RL}=8 \Omega$ |  | 10 | 1000 | nA |
| Voo | Output Offset Voltage No input signal, $\mathrm{RL}=8 \Omega$ |  | 5 | 20 | mV |
| Po | Output Power $\mathrm{THD}=1 \% \operatorname{Max}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ |  | 0.7 |  | W |
| THD + N | $\begin{aligned} & \text { Total Harmonic Distortion + Noise } \\ & \qquad \text { Po }=250 \mathrm{~mW} \mathrm{rms}, \mathrm{Gv}=2,20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, \mathrm{RL}=8 \Omega \end{aligned}$ |  | 0.15 |  | \% |
| PSRR | Power Supply Rejection Ratio ${ }^{2)}$ $\mathrm{f}=217 \mathrm{~Hz}, \mathrm{RL}=8 \Omega \text {, RFeed }=22 \mathrm{~K} \Omega \text {, Vripple }=200 \mathrm{mV} \mathrm{rms}$ |  | 75 |  | dB |
| $\Phi_{M}$ | Phase Margin at Unity Gain $\mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ |  | 70 |  | Degrees |
| GM | Gain Margin $\mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ |  | 20 |  | dB |
| GBP | Gain Bandwidth Product $\mathrm{R}_{\mathrm{L}}=8 \Omega$ |  | 2 |  | MHz |

1. Standby mode is actived when Vstdby is tied to Vcc
2. Dynamic measurements $-20^{*} \log (r m s($ Vout $) / r m s(V r i p p l e))$. Vripple is the surimposed sinus signal to $V c c @ f=217 \mathrm{~Hz}$
$\mathrm{V}_{\mathrm{CC}}=+\mathbf{3 . 3 V}, G N D=\mathbf{0 V}, \mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$ (unless otherwise specified) ${ }^{3}$ )

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{cc}}$ | Supply Current <br> No input signal, no load |  | 5.5 | 8 | mA |
| $I_{\text {Standby }}$ | Standby Current ${ }^{1)}$ <br> No input signal, Vstdby $=\mathrm{Vcc}, \mathrm{RL}=8 \Omega$ |  | 10 | 1000 | nA |
| Voo | Output Offset Voltage No input signal, $\mathrm{RL}=8 \Omega$ |  | 5 | 20 | mV |
| Po | $\begin{aligned} & \text { Output Power } \\ & \quad \text { THD }=1 \% \text { Max, } f=1 \mathrm{kHz}, R L=8 \Omega \end{aligned}$ |  | 300 |  | mW |
| THD + N | Total Harmonic Distortion + Noise $\mathrm{Po}=250 \mathrm{~mW}$ rms, $\mathrm{Gv}=2,20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ |  | 0.15 |  | \% |
| PSRR | Power Supply Rejection Ratio ${ }^{2)}$ $\mathrm{f}=217 \mathrm{~Hz}, \mathrm{RL}=8 \Omega$, RFeed $=22 \mathrm{~K} \Omega$, Vripple $=200 \mathrm{mV}$ rms |  | 75 |  | dB |
| $\Phi_{\mathrm{M}}$ | Phase Margin at Unity Gain $\mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ |  | 70 |  | Degrees |
| GM | Gain Margin $\mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ |  | 20 |  | dB |
| GBP | Gain Bandwidth Product $\mathrm{R}_{\mathrm{L}}=8 \Omega$ |  | 2 |  | MHz |

1. Standby mode is actived when Vstdby is tied to Vcc
2. Dynamic measurements $-20^{\star} \log (r m s($ Vout $) / \mathrm{rms}($ Vripple)). Vripple is the surimposed sinus signal to Vcc @f=217Hz
3. All electrical values are made by correlation between 2.6 V and 5 V measurements

## ELECTRICAL CHARACTERISTICS

$\mathrm{V}_{\mathrm{CC}}=2.6 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Symbol | Parameter | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{cc}}$ | Supply Current <br> No input signal, no load |  | 5.5 | 8 | mA |
| $\mathrm{I}_{\text {StandBy }}$ | Standby Current ${ }^{1)}$ <br> No input signal, Vstdby $=\mathrm{Vcc}, \mathrm{RL}=8 \Omega$ |  | 10 | 1000 | nA |
| Voo | Output Offset Voltage <br> No input signal, $\mathrm{RL}=8 \Omega$ |  | 5 | 20 | mV |
| Po | Output Power $\mathrm{THD}=1 \% \mathrm{Max}, \mathrm{f}=1 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ |  | 180 |  | mW |
| THD + N | Total Harmonic Distortion + Noise $\mathrm{Po}=200 \mathrm{~mW} \mathrm{rms}, \mathrm{Gv}=2,20 \mathrm{~Hz}<\mathrm{f}<20 \mathrm{kHz}, \mathrm{RL}=8 \Omega$ |  | 0.15 |  | \% |
| PSRR | Power Supply Rejection Ratio ${ }^{2)}$ $\mathrm{f}=217 \mathrm{~Hz}, \mathrm{RL}=8 \Omega$, RFeed $=22 \mathrm{~K} \Omega$, Vripple $=200 \mathrm{mV} \mathrm{rms}$ |  | 75 |  | dB |
| $\Phi_{\mathrm{M}}$ | Phase Margin at Unity Gain $R_{L}=8 \Omega, C_{L}=500 \mathrm{pF}$ |  | 70 |  | Degrees |
| GM | Gain Margin $\mathrm{R}_{\mathrm{L}}=8 \Omega, \mathrm{C}_{\mathrm{L}}=500 \mathrm{pF}$ |  | 20 |  | dB |
| GBP | Gain Bandwidth Product $\mathrm{R}_{\mathrm{L}}=8 \Omega$ |  | 2 |  | MHz |

1. Standby mode is actived when Vstdby is tied to Vcc
2. Dynamic measurements - 20*log(rms(Vout)/rms(Vripple)). Vripple is the surimposed sinus signal to Vcc @ $f=217 \mathrm{~Hz}$

| Components | Functional Description |
| :---: | :--- |
| Rin | Inverting input resistor which sets the closed loop gain in conjunction with Rfeed. This resistor also <br> forms a high pass filter with Cin (fc $=1 /(2 \times \mathrm{Pi} \times$ Rin $\times$ Cin $))$ |
| Cin | Input coupling capacitor which blocks the DC voltage at the amplifier input terminal |
| Rfeed | Feed back resistor which sets the closed loop gain in conjunction with Rin |
| Cs | Supply Bypass capacitor which provides power supply filtering |
| Cb | Bypass pin capacitor which provides half supply filtering |
| Cfeed | Low pass filter capacitor allowing to cut the high frequency <br> (low pass filter cut-off frequency $1 /(2 \times$ Pi $\times$ Rfeed $\times$ Cfeed $))$ |
| Rstb | Pull-up resistor which fixes the right supply level on the standby pin |
| Gv | Closed loop gain in BTL configuration $=2 \times$ (Rfeed / Rin) |

## REMARKS

1. All measurements, except PSRR measurements, are made with a supply bypass capacitor $\mathrm{Cs}=100 \mu \mathrm{~F}$.
2. The standby response time is about $1 \mu \mathrm{~s}$.

Fig. 1 : Open Loop Frequency Response


Fig. 3 : Open Loop Frequency Response


Fig. 5 : Open Loop Frequency Response


Fig. 2 : Open Loop Frequency Response


Fig. 4 : Open Loop Frequency Response


Fig. 6 : Open Loop Frequency Response


Fig. 7 : Open Loop Frequency Response


Fig. 8 : Open Loop Frequency Response


Fig. 9 : Open Loop Frequency Response


Fig. 10 : Power Supply Rejection Ratio (PSRR) vs Power supply


Fig. 12 : Power Supply Rejection Ratio (PSRR) vs Bypass Capacitor


Fig. 14 : Power Supply Rejection Ratio (PSRR) vs Feedback Resistor


Fig. 11 : Power Supply Rejection Ratio (PSRR) vs Feedback Capacitor


Fig. 13 : Power Supply Rejection Ratio (PSRR) vs Input Capacitor


Fig. 15 : Pout @ THD + N = 1\% vs Supply Voltage vs RL


Fig. 17 : Power Dissipation vs Pout


Fig. 19 : Power Dissipation vs Pout


Fig. 16 : Pout @ THD + N = 10\% vs Supply Voltage vs RL


Fig. 18 : Power Dissipation vs Pout


Fig. 20 : Power Derating Curves


Fig. 21 : Output Power vs Load Resistance


Fig. 23 : Clipping Voltage vs Supply Voltage


Fig. 25 : Noise Floor



Fig. 22 : Output Power vs Load Resistance


Fig. 24 : Frequency response vs Cin \& Cfeed


Fig. 26 : THD + N vs Output Power


Fig. 28 : THD + N vs Output Power


Fig. 30 : THD + N vs Output Power


Fig. 27 : THD + N vs Output Power


Fig. 29 : THD + N vs Output Power


Fig. 31 : THD + N vs Output Power


Fig. 32 : THD + N vs Output Power


Fig. 34 : THD + N vs Output Power


Fig. 36 : THD + N vs Output Power


Fig. 33 : THD + N vs Output Power


Fig. 35 : THD + N vs Output Power


Fig. 37 : THD + N vs Output Power


Fig. 38 : THD + N vs Output Power


Fig. 40 : THD + N vs Output Power


Fig. 42 : THD + N vs Output Power


Fig. 39 : THD + N vs Output Power


Fig. 41 : THD + N vs Output Power


Fig. 43 : THD + N vs Output Power


Fig. 44 : Signal to Noise Ratio vs Power Supply with Unweighted Filter ( $\mathbf{2 0 H z}$ to 20kHz)


Fig. 46 : Signal to Noise Ratio vs Power Supply with Weighted Filter type A


Fig. 48 : Current Consumption vs Power Supply Voltage


Fig. 45 : Signal to Noise Ratio Vs Power Supply with Unweighted Filter ( $\mathbf{2 0 H z}$ to $\mathbf{2 0 k H z}$ )


Fig. 47 : Signal to Noise Ratio vs Power Supply with Weighted Filter Type A


Fig. 49 : Current Consumption vs Standby Voltage @ Vcc=5V


Fig. 50 : Current Consumption vs Standby Voltage @ Vcc=3.3V


Fig. 51 : Current Consumption vs Standby Voltage @ Vcc = 2.6V


## ■ BTL Configuration Principle

The TS4900 is a monolithic power amplifier with a BTL (Bridge Tied Load) output configuration. BTL means that each end of the load is connected to two single ended output amplifiers. Thus, we have:

Single ended output $1=$ Vout $=\operatorname{Vout}(\mathrm{V})$
Single ended output $2=\operatorname{Vout} 2=-\operatorname{Vout}(\mathrm{V})$
And Vout1 - Vout2 $=2$ Vout (V)
The output power is :

$$
\text { Pout }=\frac{\left(2 \text { Vout }_{\text {RMS }}\right)^{2}}{R_{L}}(W)
$$

For the same power supply voltage, the output power in BTL configuration is four times higher than the output power in single ended configuration.

## Gain In Typical Application Schematic

 (cf. page 1)In flat region (no effect of Cin), the output voltage of the first stage is :

$$
\text { Vout1 }=- \text { Vin } \frac{\text { Rfeed }}{\text { Rin }}(V)
$$

For the second stage : Vout2 $=-$ Vout1 $(\mathrm{V})$
The differential output voltage is

$$
\text { Vout2 }- \text { Vout1 }=2 \text { Vin } \frac{\text { Rfeed }}{\text { Rin }}(\text { V })
$$

The differential gain named gain (Gv) for more convenient usage is :

$$
\text { Gv }=\frac{\text { Vout2 - Vout1 }}{\text { Vin }}=2 \frac{\text { Rfeed }}{\text { Rin }}
$$

Remark : Vout2 is in phase with Vin and Vout1 is 180 phased with Vin. It means that the positive terminal of the loudspeaker should be connected to Vout2 and the negative to Vout1.

## - Low and high frequency response

In low frequency region, the effect of Cin starts. Cin with Rin forms a high pass filter with a -3dB cut off frequency

$$
\mathrm{FCL}=\frac{1}{2 \pi \operatorname{Rin} \mathrm{Cin}}(\mathrm{~Hz})
$$

In high frequency region, you can limit the
bandwidth by adding a capacitor (Cfeed) in parallel with Rfeed. Its form a low pass filter with a -3 dB cut off frequency

$$
\mathrm{FcH}=\frac{1}{2 \pi \text { Rfeed Cfeed }}(\mathrm{Hz})
$$

$\square$ Power dissipation and efficiency
Hypothesis:

- Voltage and current in the load are sinusoidal (Vout and lout)
- Supply voltage is a pure DC source (Vcc)

Regarding the load we have:

$$
\text { VOUT }=\mathrm{V}_{\text {PEAK }} \sin \omega t(\mathrm{~V})
$$

and

$$
\text { IOUT }=\frac{\text { VOUT }}{R L}(A)
$$

and

$$
\text { POUT }=\frac{\text { VPEAK }^{2}}{2 R L}(W)
$$

Then, the average current delivered by the supply voltage is:

$$
I C C_{A V G}=2 \frac{V P E A K}{\pi R L}(A)
$$

The power delivered by the supply voltage is Psupply = Vcc Iccavg (W)

Then, the power dissipated by the amplifier is Pdiss = Psupply - Pout (W)

$$
\text { Pdiss }=\frac{2 \sqrt{2 V C C}}{\pi \sqrt{R L}} \sqrt{\text { POUT }}-\text { Pout }(W)
$$

and the maximum value is obtained when:

$$
\frac{\partial \text { Pdiss }}{\partial \text { Pout }}=0
$$

and its value is:

$$
\text { Pdissmax }=\frac{2 V_{c c^{2}}}{\pi^{2} R_{L}}(\mathrm{~W})
$$

Remark: This maximum value is only depending on power supply voltage and load values.

The efficiency is the ratio between the output
power and the power supply

$$
\eta=\frac{\text { POUT }}{\text { Psupply }}=\frac{\pi \mathrm{V} \text { PEAK }}{4 \mathrm{VCC}}
$$

The maximum theoretical value is reached when Vpeak $=\mathrm{Vcc}$, so

$$
\frac{\pi}{4}=78.5 \%
$$

## Decoupling of the circuit

Two capacitors are needed to bypass properly the TS4900, a power supply bypass capacitor Cs and a bias voltage bypass capacitor Cb .

Cs has especially an influence on the THD +N in high frequency (above 7 kHz ) and indirectly on the power supply disturbances.
With $100 \mu \mathrm{~F}$, you can expect similar THD +N performances like shown in the datasheet.

If Cs is lower than $100 \mu \mathrm{~F}$, in high frequency increases, THD +N and disturbances on the power supply rail are less filtered.
To the contrary, if Cs is higher than $100 \mu \mathrm{~F}$, those disturbances on the power supply rail are more filtered.

Cb has an influence on THD +N in lower frequency, but its function is critical on the final result of PSRR with input grounded in lower frequency.

If Cb is lower than $1 \mu \mathrm{~F}$, THD +N increase in lower frequency (see THD+N vs frequency curves) and the PSRR worsens up
If Cb is higher than $1 \mu \mathrm{~F}$, the benefit on $\mathrm{THD}+\mathrm{N}$ in lower frequency is small but the benefit on PSRR is substantial (see PSRR vs. Cb curve : fig.12).

Note that Cin has a non-negligible effect on PSRR in lower frequency. Lower is its value, higher is the PSRR (see fig. 13).

## - Pop and Click performance

Pop and Click performance is intimately linked with the size of the input capacitor Cin and the bias voltage bypass capacitor Cb .

Size of Cin is due to the lower cut-off frequency and PSRR value requested. Size of Cb is due to THD+N and PSRR requested always in lower frequency.

Moreover, Cb determines the speed that the amplifier turns ON. The slower the speed is, the softer the turn ON noise is.

The charge time of Cb is directly proportional to the internal generator resistance $50 \mathrm{k} \Omega$.
Then, the charge time constant for Cb is
$\tau \mathrm{b}=50 \mathrm{k} \Omega \mathrm{xCb}$ (s)
As Cb is directly connected to the non-inverting input (pin 2 \& 3) and if we want to minimize, in amplitude and duration, the output spike on Vout1 (pin 5), Cin must be charged faster than Cb. The charge time constant of Cin is
$\boldsymbol{\tau} \mathbf{i n}=($ Rin + Rfeed $) \times$ Cin ( s$)$
Thus we have the relation
$\tau$ in $\ll \tau$ b (s)
The respect of this relation permits to minimize the pop and click noise.

Remark : Minimize Cin and Cb has a benefit on pop and click phenomena but also on cost and size of the application.

Example : your target for the -3dB cut off frequency is 100 Hz . With Rin=Rfeed=22 k $\Omega$, Cin= $=72 \mathrm{nF}$ (in fact 82 nF or 100 nF ).
With $\mathrm{Cb}=1 \mu \mathrm{~F}$, if you choose the one of the latest two values of Cin, the pop and click phenomena at power supply ON or standby function ON/OFF will be very small
$50 \mathrm{k} \Omega \times 1 \mu \mathrm{~F} \gg 44 \mathrm{k} \Omega \times 100 \mathrm{nF}$ ( $50 \mathrm{~ms} \gg 4.4 \mathrm{~ms}$ ).
Increasing Cin value increases the pop and click phenomena to an unpleasant sound at power supply ON and standby function ON/OFF.

Why Cs is not important in pop and click consideration?

Hypothesis:

- Cs $=100 \mu \mathrm{~F}$
- Supply voltage $=5 \mathrm{~V}$
- Supply voltage internal resistor $=0.1 \Omega$
- Supply current of the amplifier Icc $=6 \mathrm{~mA}$

At power ON of the supply, the supply capacitor is charged through the internal power supply resistor. So, to reach 5 V you need about five to ten times the charging time constant of Cs ( $\tau \mathrm{s}=$ $0.1 \mathrm{xCs}(\mathrm{s})$ ).
Then, this time equal $50 \mu \mathrm{~s}$ to $100 \mu \mathrm{~s} \ll \tau$ b in the majority of application.

At power OFF of the supply, Cs is discharged by a constant current Icc. The discharge time from 5 V to 0 V of Cs is

$$
\mathrm{tDischCs}=\frac{5 \mathrm{Cs}}{\mathrm{Icc}}=83 \mathrm{~ms}
$$

Now, we must consider the discharge time of Cb . At power OFF or standby ON, Cb is discharged by a $100 \mathrm{k} \Omega$ resistor. So the discharge time is about $\tau \mathrm{b}_{\text {Disch }} \approx 3 \mathrm{xCbx} 100 \mathrm{k} \Omega$ (s).
In the majority of application, $\mathrm{Cb}=1 \mu \mathrm{~F}$, then $\tau \mathrm{b}_{\text {Disch }} \approx 300 \mathrm{~ms} \gg \mathrm{t}_{\text {dischCs }}$.

## - How to use the PSRR curves (page 7)

We have finished a design and we have chosen the components values :

- Rin $=$ Rfeed $=22 k \Omega$, Cin $=100 n F, C b=1 \mu F$

Now, on fig. 13, we can see the PSRR (input grounded) vs frequency curves. At 217 Hz we have a PSRR value of -36 dB .
In fact, we want a value of about -70 dB . So, we need a gain of +34 dB !
Now, on fig. 12 we can see the effect of Cb on the PSRR (input grounded) vs. frequency. With $\mathrm{Cb}=100 \mu \mathrm{~F}$, we can reach the -70 dB value.

The process to obtain the final curve $(\mathrm{Cb}=100 \mu \mathrm{~F}$, Cin=100nF, Rin=Rfeed $=22 \mathrm{k} \Omega$ ) is a simple transfer point by point on each frequency of the curve on fig. 13 to the curve on fig. 12.
The measurement result is shown on figure $A$.
Fig. A : PSRR changes with Cb


## Remark on PSRR measurement conditions

## What is the PSRR ?

The PSRR is the Power Supply Rejection Ratio. It's a kind of SVR in a determined frequency range. The PSRR of a device is the ratio between the power supply disturbance and the result on the output. We can say that the PSRR is the ability of a device to minimize the impact of power supply disturbances to the output.

How do we measure the PSRR?
Fig. B : PSRR measurement schematic


## - Measurement process:

- Fix the DC voltage supply (Vcc)
- Fix the AC sinusoidal ripple voltage (Vripple)
- No bypass capacitor Cs is used

The PSRR value for each frequency is :

Remark : The measurement of the RMS voltage is not a selective RMS measurement but a full range ( 2 Hz to 125 kHz ) RMS measurement. This means we have: the effective RMS signal + the noise.

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)


| Dim. | Millimeters |  |  | Inches |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A |  |  | 1.75 |  |  | 0.069 |
| a1 | 0.1 |  | 0.25 | 0.004 |  | 0.010 |
| a2 |  |  | 1.65 |  |  | 0.065 |
| a3 | 0.65 |  | 0.85 | 0.026 |  | 0.033 |
| b | 0.35 |  | 0.48 | 0.014 |  | 0.019 |
| b1 | 0.19 |  | 0.25 | 0.007 |  | 0.010 |
| C | 0.25 |  | 0.5 | 0.010 |  | 0.020 |
| c1 | $45^{\circ}$ (typ.) |  |  |  |  |  |
| D | 4.8 |  | 5.0 | 0.189 |  | 0.197 |
| E | 5.8 |  | 6.2 | 0.228 |  | 0.244 |
| e |  | 1.27 |  |  | 0.050 |  |
| e3 |  | 3.81 |  |  | 0.150 |  |
| F | 3.8 |  | 4.0 | 0.150 |  | 0.157 |
| L | 0.4 |  | 1.27 | 0.016 |  | 0.050 |
| M |  |  | 0.6 |  |  | 0.024 |
| S | $8^{\circ}$ (max.) |  |  |  |  |  |

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (miniSO)


| Dim. | Millimeters |  |  | Inches |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A |  |  | 1.100 |  |  | 0.043 |
| A1 | 0.050 | 0.100 | 0.150 | 0.002 | 0.004 | 0.006 |
| A2 | 0.780 | 0.860 | 0.940 | 0.031 | 0.034 | 0.037 |
| b | 0.250 | 0.330 | 0.400 | 0.010 | 0.013 | 0.016 |
| c | 0.130 | 0.180 | 0.230 | 0.005 | 0.007 | 0.009 |
| D | 2.900 | 3.000 | 3.100 | 0.114 | 0.118 | 0.122 |
| E | 4.750 | 4.900 | 5.050 | 0.187 | 0.193 | 0.199 |
| E1 | 2.900 | 3.000 | 3.100 | 0.114 | 0.118 | 0.122 |
| e |  | 0.650 |  |  | 0.026 |  |
| L | 0.400 | 0.550 | 0.700 | 0.016 | 0.022 | 0.028 |
| L1 |  | 0.950 |  |  | 0.037 |  |
| k | 0 d | 3d | 6 d | 0 d | 3 d | 6 d |
| Ccc |  |  | 0.100 |  |  | 0.004 |

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[^0]:    1. This thermal resistance can be reduced with a suitable PCB layout (see Power Derating Curves)
